

Description

The Si501/2/3/4 CMEMS programmable oscillator series combines standard CMOS + MEMS in a single, monolithic IC to provide high-quality and high-reliability oscillators. Each device is specified for guaranteed performance across voltage, process, temperature, shock, vibration and aging for 10 years. More information on CMEMS available at www.silabs.com/cmems.

Applications: General purpose microcontrollers, industrial control, IP cameras, surveillance systems, metering, home and office automation, security systems, sleep clocking, 10/100 Ethernet/EtherCAT, SPI, SAS3.0 / SATA3.0, PCIe ref clock, NVMe, HDD, SSD, hybrid storage, DDR3/3L, USB2.0, USB OTG/2.0, M2M, HDMI

Not recommended: Wi-Fi, Bluetooth, USB 3.0, Gigabit Ethernet

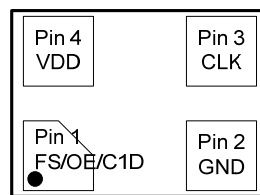
Features

- Any frequency oscillator from 32 kHz to 100 MHz
 - Contact Silicon Labs Marketing for frequencies above 100 MHz
- Frequency stability: $\pm 20/\pm 30/\pm 50$ ppm including 10-year aging
 - 20 to +70 °C: Extended Commercial
 - 40 to +85 °C: Industrial
- Highly configurable: low power vs. low jitter, frequency, F_{STAB} , T_R/T_F , V_{DD} , OE/FS functionality (see ordering guide below)
- In-circuit programmable via C1D 1-pin interface (Si504)
- Seamless V_{DD} from +1.71 to +3.63 V
- Low period jitter mode / low power mode
- Glitchless start and stop
- RoHS compliant, Pb-free

Product Selector Guide

Part Number	Description	Control
Si501	Single frequency	OE
Si502	Dual frequency	FS/OE
Si503	Quad frequency	FS
Si504	Programmable for any supported frequency or configuration	C1D 1-pin interface (see Si504 data sheet for details)

Pin-out



(top view)

Pin Description

Pin Number	Description
1	FS = Frequency Select OE = Output Enable C1D = Single wire interface
2	GND = Ground
3	CLK = Clock out
4	VDD = Power Supply

Ordering Guide

	VDD	TYP T_R/T_F	Jitter vs Power
A	1.7-3.6	0.7 ns ¹	Low Power
B	3.3V	1.3 ns ²	
C	2.5V	1.3 ns ²	
D	1.8V	1.3 ns ²	
E	1.7-3.6	3 ns ³	
F	1.7-3.6	5 ns ³	
G	1.7-3.6	8 ns ³	
H	1.7-3.6	0.7 ns ¹	Low Jitter
J	3.3V	1.3 ns ²	
K	2.5V	1.3 ns ²	
L	1.8V	1.3 ns ²	
M	1.7-3.6	3 ns ³	
N	1.7-3.6	5 ns ³	
P	1.7-3.6	8 ns ³	

501			
	OE High	OE Low	Internal Pull Resistor
A	Enable	Stop	Pull-Up
B	Enable	Doze	
C	Enable	Sleep	
D	Stop	Enable	Pull-Down
E	Doze		
F	Sleep	None	
G	Enable		Stop
H			Doze
J	Enable	Sleep	
K	Stop	None	
L	Doze		
M	Sleep		

502 ⁶		
	OE Low	Internal Pull Resistor
A	Stop	Pull-Up
B	Doze	
C	Sleep	
D	Stop	None
E	Doze	
F	Sleep	

503	
	Pull Resistor
A	Pull-Up
B	None

504	
	Pull-Up only
A	Pull-Up only

504 only ⁵	
	Maximum F_{OUT}
A	0.032 – 80 MHz
B	0.032 – 100 MHz

	Temp Range
F	-20 to 70 °C
G	-40 to 85 °C

OPN Prefix	Description
501	Single frequency
502	Dual frequency
503	Quad frequency
504	Any frequency

ppm	
A	± 50
B	± 30
C	± 20

OPN	Freq Code	Description
501 only	Mxxxxxx	$f_{OUT} < 1$ MHz
	xMxxxxx	$1 \text{ MHz} \leq f_{OUT} < 10$ MHz
	xxMxxxx	$10 \text{ MHz} \leq f_{OUT} < 100$ MHz
	100M000	$f_{OUT} = 100$ MHz
501/2/3/4	xxxxxxx	Silicon Labs 6-digit code for 502/3/4, or >6-decimal freq on 501

	Reel
R	Reel
	Cut Tape

	Package Dimension
B	3.2 x 5 mm ⁴
C	2.5 x 3.2 mm
D	2 x 2.5 mm

50X - - - - - A - R

Ordering Guide Notes:

- Series termination resistor (R_S – see Apps Circuits section) is recommended for this configuration.
- Series termination resistor (R_S) is not needed for this configuration. Output impedance is 50Ω for the indicated supply condition.
- Series termination resistor (R_S) is not needed for this configuration. Reduced EMI setting.
- 3.2 x 5 mm package is delivered as 3.2 x 4 mm and accommodates the industry-standard 3.2 x 5 mm footprint.
- Select option to support maximum anticipated frequency needed.
- The Si502 OE pin has three (3) states: OE High = Freq 1; OE Weak High = Freq 2; OE Low is configurable.

Selected Electrical Specifications

$V_{DD} = +1.71\text{ V to }+3.63\text{ V}$, $T_A = -40\text{ to }85\text{ °C}$ unless stated otherwise.

Parameter	Symbol	Test Condition/Comment	Min	Typ	Max	Unit
Frequency Range	F_{CLK}	Programmable family range	0.032	—	100	MHz
Supply Voltage	V_{DD}	Supports continuous V_{DD} from Min to Max	1.71	—	3.63	V
Supply Current	I_{DD1}	$3.3 V_{DD}$, $F_{CLK} = 1\text{ MHz}$, 4 pF, Low Power mode	—	1.7	2.5	mA
		$3.3 V_{DD}$, $F_{CLK} = 1\text{ MHz}$, 4 pF, Low Jitter mode	—	3.9	4.9	mA
Static Supply Current ¹	I_{DD2}	Stop mode, $F_{CLK} = 1\text{ MHz}$, Low Power mode	—	1.7	2.5	mA
		Stop mode, $F_{CLK} = 1\text{ MHz}$, Low Jitter mode	—	3.9	4.9	mA
		Doze mode	—	670	890	μA
		Sleep mode	—	0.3	1	μA
Frequency Stability ²	F_{STAB}	$T_A = -20\text{ °C to }+70\text{ °C}$, $-40\text{ °C to }+85\text{ °C}$	-20	—	+20	ppm
			-30	—	+30	ppm
			-50	—	+50	ppm
CMOS Rise/Fall Time ³	T_R/T_F	1 st option code = A ⁴ or H ⁴	0.4	0.7	1.2	ns
		1 st option code = B, C, D, J, K, L	1	1.3	1.6	ns
		1 st option code = E, M	2	3	4	ns
		1 st option code = F, N	4	5	7	ns
		1 st option code = G, P	7	8	11	ns
Cycle-to-Cycle Jitter	J_{CCPP}	$F_{CLK} = 100\text{ MHz}$, Low Jitter mode 1 st option code = H	—	14	25	ps pk-pk
Period Jitter Pk-Pk	J_{PPPKPK}	$F_{CLK} = 100\text{ MHz}$, Low Jitter mode 1 st option code = H	—	9	13	ps pk-pk
Period Jitter	J_{PRMS}	$F_{CLK} = 100\text{ MHz}$, Low Jitter mode 1 st option code = H	—	1	1.6	ps rms
Phase Jitter ⁵	ϕ	$F_{CLK} = 75\text{ MHz}$, $F_{OFFSET} = 900\text{ kHz} - 7.5\text{ MHz}$ Low Jitter mode, 1 st option code = H	—	1	1.3	ps rms
Duty Cycle	DC	Drive strength selected such that T_R/T_F (20% to 80%) < 10% of period	45	50	55	%
Input High Voltage	V_{IH}		$0.7 \times V_{DD}$	—	—	V
Input Low Voltage	V_{IL}		—	—	$0.3 \times V_{DD}$	V
Output High Voltage	V_{OH}		$0.9 \times V_{DD}$	—	—	V
Output Low Voltage	V_{OL}		—	—	$0.1 \times V_{DD}$	V

- Si501 supports OE/mode functionality. Si502 supports OE/mode and FS functionality. Si503 supports only FS functionality. See data sheet functional description section for more information.
- Frequency stability includes initial tolerance, solder shift, operating temp range, rated power supply voltage change, load change, 10-year aging, shock, and vibration.
- $C_L = 15\text{ pF}$, T_R/T_F (20% to 80%), 3.3 V unless otherwise stated. See datasheet for additional T_R/T_F options.
- Recommended series termination resistor (R_S) = 24.9 Ω for $Z_0=50\ \Omega$.
- Integrated phase jitter exceeds some high-performance data communications system requirements. See AN783 for more information.

Absolute Maximum Ratings¹

Parameter	Symbol	Condition	Rating	Unit
Storage Temperature	T_S		-55 to 125	°C
Supply Voltage	V_{DD}		-0.5 to 3.8	°C
Input Voltage	V_{IN}		$0.5\text{ to }V_{DD} + 0.3$	V
ESD HBM (JESD22-A114)	HBM		2000	V
ESD CDM	CDM		500	V
Solder Temp ²	T_{PEAK}		260	°C
Solder Time at T_{PEAK} ²	T_P		20-40	s
Max Junction Temp	T_J		125	°C

- Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.
- The device is compliant with JEDEC J-STD-020.

Environmental Compliance and Package Information

Parameter	Test Condition
Mechanical Shock	MIL-STD-883, M2002 Cond B. (1,500g)
Mechanical Shock High g	MIL-STD-883, M2002, Cond. E (10,000g)
Mechanical Vibration	MIL-STD-883, Method 2007
Solderability	MIL-STD-883, Method 2003
Temperature Cycle	JESD22, Method A104
Resistance to Solder Heat	MIL-STD-883, Method 2036
Contact Pads	Gold over Nickel/Palladium

Thermal Conditions

Parameter	Symbol	Test Condition	Value	Unit
Thermal Impedance	Θ_{JA}	3.2 x 5 mm, still air	187	°C/W
		2.5 x 3.2 mm, still air	239	
		2 x 2.5 mm, still air	241	

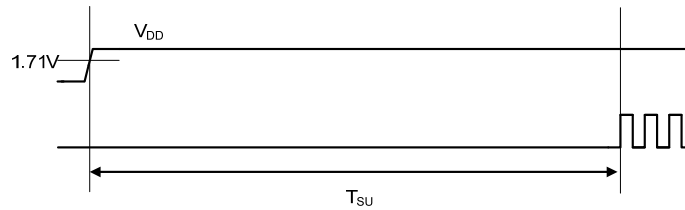
Clock Timing Characteristics

$V_{DD} = +1.71\text{ V to }+3.63\text{ V}$, $T_A = -40\text{ to }85\text{ °C}$ unless stated otherwise.

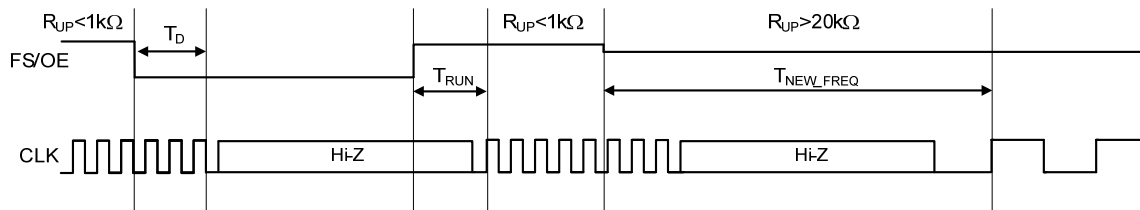
Parameter	Symbol	Test Condition/Comment	Min	Typ	Max	Unit
Startup Time ¹	T_{SU}	From V_{DD} crossing 1.71 to first clock	—	2.5	4	ms
Resume Time ^{2,3}	T_{RUN}	From Stop mode	—	—	$1.5 \times T_{CLK} + 35$	ns
		From Sleep mode	—	2.5	5	ms
		From Doze mode	—	—	2.55	
Output Disable Time ^{2,3}	T_D	To Stop	—	—	$1.5 \times T_{CLK} + 35$	ns
		To Sleep/Doze	—	—	225	μs
Frequency Update Time ²	T_{NEW_FREQ}	To New Frequency	—	—	5	ms

1. Hold FS/OE high (strong or weak) during powerup for fastest time to clock.
2. Si501 and Si502 only. Si503 has frequency select (FS) only and does not support Stop, Doze or Sleep.
3. $T_{CLK} = \text{clock period} = 1 / F_{CLK}$.

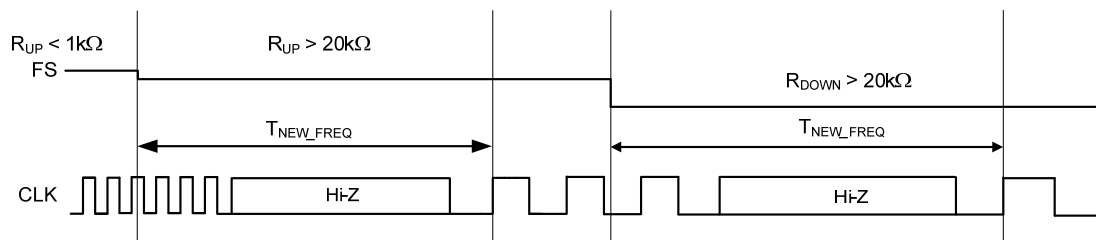
AC Waveforms



Si501/2/3 Power On Time

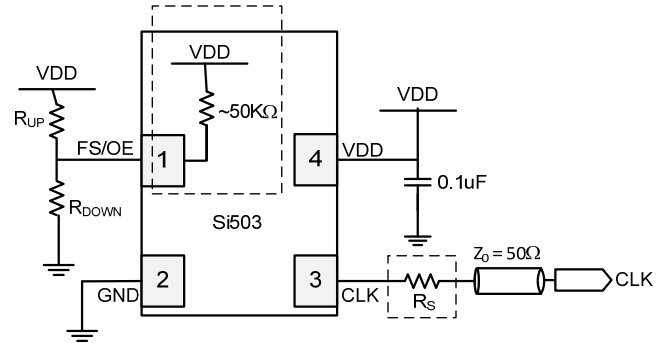
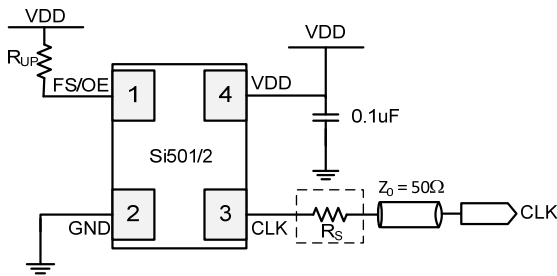


Si501/2 AC Waveform



Si503 AC Waveform

Applications Circuits



Si501/2 Apps Circuit w/ Optional Series Resistor

Si503 Apps Circuit w/ Configurable Options

Notes:

1. Dotted line boxes show optional components depending on configuration options. See data sheet for additional information and for applications using a microcontroller. Data sheet is available at www.silabs.com/cmems.
2. Recommended series termination resistor (R_S) = 24.9 Ω for Z₀ = 50 Ω.

Si502 FS/OE States and Resistor Values

FS/OE State	R _{UP}	Clock Output
Strong High	0 Ω ≤ R _{UP} ≤ 1 kΩ	Frequency 1
Weak High	20 kΩ ≤ R _{UP} ≤ 200 kΩ	Frequency 2
Low	—	Hi-Z

Si503 FS States and Resistor Values

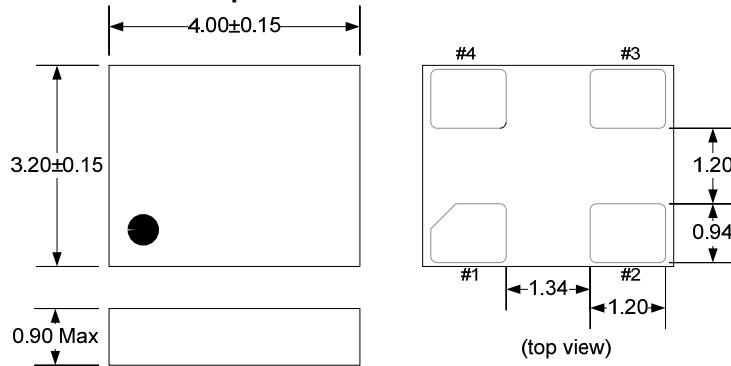
FS/OE State	R _{UP}	R _{DOWN}	Clock Output
Strong High	0 Ω ≤ R _{UP} ≤ 1 kΩ	No pop	Frequency 1
Weak High	20 kΩ ≤ R _{UP} ≤ 200 kΩ	No pop	Frequency 2
Weak Low	No pop	20 kΩ ≤ R _{DOWN} ≤ 200 kΩ	Frequency 3
Low	No pop	0 Ω ≤ R _{DOWN} ≤ 1 kΩ	Frequency 4

Notes for both FS/OE tables above:

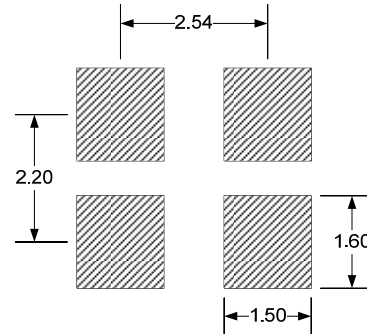
1. If the internal pull-up resistor order option is NOT selected, an MCU internal pull-up resistor or an external pull-up resistor should be used. See data sheet for more information.
2. The parallel combination of all pull-up resistors on the FS/OE pin including the optional internal pull-up resistor must be > 20 kΩ to select Weak High.
3. If the Si50x internal pull-up resistor is enabled with no other external OE connections, the OE state will be detected as "Weak High", selecting Frequency 2 by default.

Package Dimensions and Landing Patterns

3.2 mm x 5 mm 4-pin DFN Dimensions

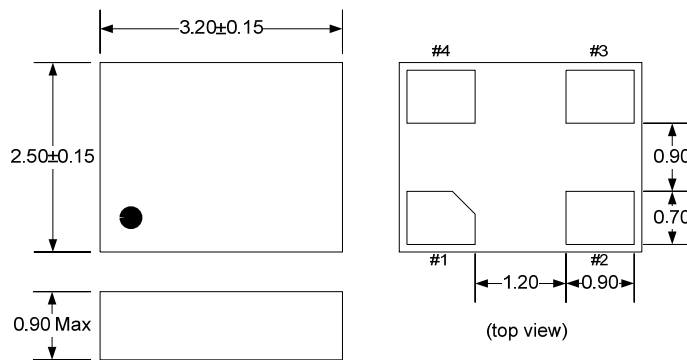


3.2 mm x 5 mm 4-pin DFN Landing Pattern

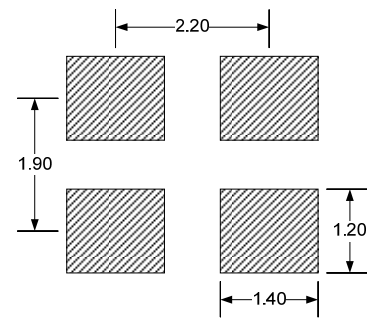


Note: The 3.2 x 5 mm package is delivered as a 3.2 x 4 mm package and is drop-in compatible to industry-standard 3.2 x 5 landing patterns.

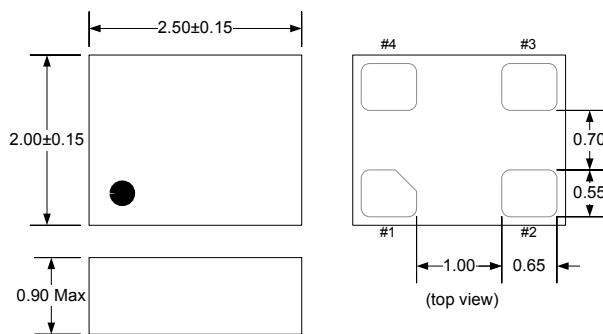
2.5 mm x 3.2 mm 4-pin DFN Dimensions



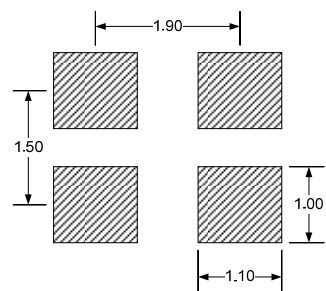
2.5 mm x 3.2 mm 4-pin DFN Landing Pattern



2 mm x 2.5 mm 4-pin DFN Dimensions

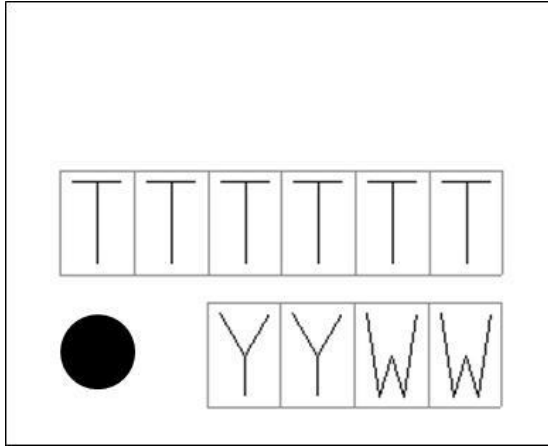


2 mm x 2.5 mm 4-pin DFN Landing Pattern



Package Top Marks and Explanations

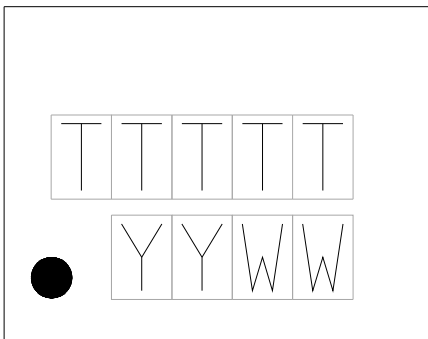
3.2 mm x 5 mm Top Mark



3.2 mm x 5 mm Top Mark Explanation

Mark Method:	Laser	
Font:	0.66 mm Right-Justified	
Line 1 Marking:	TTTTT=Trace Code	Manufacturing Code from the Assembly Purchase Order form.
Line 2 Marking:	Circle=0.5mm diameter Left-Justified	Pin 1 Indicator
	YY = Year WW = Work Week	Assigned by the Assembly House. Corresponds to the year and work week of the build date.

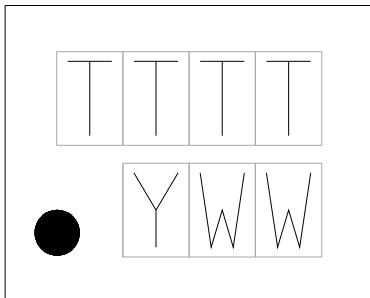
2.5 mm x 3.2 mm Top Mark



2.5 mm x 3.2 mm Top Mark Explanation

Mark Method:	Laser	
Font:	0.50 mm Right-Justified	
Line 1 Marking:	TTTT=Trace Code	Manufacturing Code from the Assembly Purchase Order form.
Line 2 Marking:	Circle=0.3 mm diameter Left-Justified	Pin 1 Indicator
	YY = Year WW = Work Week	Assigned by the Assembly House. Corresponds to the year and work week of the build date.

2 mm x 2.5 mm Top Mark



2 mm x 2.5 mm Top Mark Explanation

Mark Method:	Laser	
Font:	0.50 mm Right-Justified	
Line 1 Marking:	TTTT=Trace Code	Manufacturing Code from the Assembly Purchase Order form.
Line 2 Marking:	Circle=0.3 mm diameter Left-Justified	Pin 1 Indicator
	Y = Year WW = Work Week	Assigned by the Assembly House. Corresponds to the year and work week of the build date.

CONTACT INFORMATION

Silicon Laboratories Inc.

400 West Cesar Chavez

Austin, TX 78701

Tel: 1+(512) 416-8500

Fax: 1+(512) 416-9669

Toll Free: 1+(877) 444-3032

Please visit the Silicon Labs Technical Support web page:

<https://www.silabs.com/support/pages/contacttechnicalsupport.aspx>

and register to submit a technical support request.

Patent Notice

Silicon Labs invests in research and development to help our customers differentiate in the market with innovative low-power, small size, analog-intensive mixed-signal solutions. Silicon Labs' extensive patent portfolio is a testament to our unique approach and world-class engineering team.

The information in this document is believed to be accurate in all respects at the time of publication but is subject to change without notice. Silicon Laboratories assumes no responsibility for errors and omissions, and disclaims responsibility for any consequences resulting from the use of information included herein. Additionally, Silicon Laboratories assumes no responsibility for the functioning of undescribed features or parameters. Silicon Laboratories reserves the right to make changes without further notice. Silicon Laboratories makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Silicon Laboratories assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. Silicon Laboratories products are not designed, intended, or authorized for use in applications intended to support or sustain life, or for any other application in which the failure of the Silicon Laboratories product could create a situation where personal injury or death may occur. Should Buyer purchase or use Silicon Laboratories products for any such unintended or unauthorized application, Buyer shall indemnify and hold Silicon Laboratories harmless against all claims and damages.

Silicon Laboratories and Silicon Labs are trademarks of Silicon Laboratories Inc.

Other products or brandnames mentioned herein are trademarks or registered trademarks of their respective holders.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9